

LM2674 SIMPLE SWITCHER® 电源转换器、 500mA、高效降压稳压器

1 特性

- 推出的新产品：
 - LMR36506 3V 至 65V、0.6A、200kHz 至 2.2MHz 同步转换器
- 用于加快上市速度：
 - TPSM365R6 3V 至 65V、0.6A、200kHz 至 2.2MHz 电源模块
- 效率高达 96%
- 采用 8 引脚 SOIC、PDIP 和 16 引脚 WSON 封装
- 简单且易于设计
- 只需要五个外部元件
- 使用现成的标准电感器
- 3V、5V、12V 和可调输出版本
- 可调版本输出电压范围为 1.21V 至 37V
- 在线路和负载条件下具有 $\pm 1.5\%$ 的最大输出电压容差
- 可确保 500mA 输出负载电流
- 0.25 Ω DMOS 输出开关
- 8V 至 40V 的宽输入电压范围
- 260kHz 固定频率内部振荡器
- TTL 关断功能、低功耗待机模式
- 热关断和电流限制保护
- 使用 LM2674 并借助 WEBENCH® Power Designer 创建定制设计方案

2 应用

- 简单高效 (> 90%) 的降压稳压器
- 适用于线性稳压器的高效前置稳压器
- 负/正转换器

3 说明

LM2674 系列稳压器是采用 LMDMOS 工艺构建的单片集成电路。该系列稳压器提供降压开关稳压器的全部有效功能，能够驱动 500mA 负载电流，并具有出色的线性调整率和负载调整率。这些器件可提供 3.3V、5V、12V 固定输出电压和可调节输出电压版本。

这类稳压器不仅需要很少的外部元件，而且简单易用，还具有获得专利的内部频率补偿和固定频率振荡器。

LM2674 系列在 260kHz 的开关频率下运行，因此采用的滤波器元件可比更低频率的开关稳压器所需的元件尺寸更小。由于效率非常高 (> 90%)，只需通过印刷电路板上的覆铜线迹进行散热。

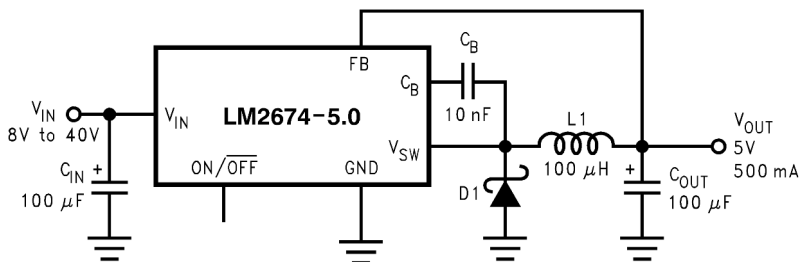
数家不同的生产商提供的标准电感器系列均可与 LM2674 搭配使用。使用这些先进的 IC，此特性极大地简化了开关模式电源的设计。数据表中还包含针对在开关模式电源中工作的二极管和电容器的选择器指南。

封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
LM2674	D (SOIC, 8)	4.90mm × 3.91mm
	P (PDIP, 8)	9.81mm × 6.35mm
	NHN (WSON, 16)	5.00mm × 5.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。



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典型应用



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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision G (June 2016) to Revision H (June 2023)	Page
• 更新了整个文档中的表格、图和交叉参考的编号格式.....	1
• 添加了与 WEBENCH 相关的信息.....	1
• 添加了指向 LMR36506 和 TPSM365R6 产品文件夹的链接.....	1
• 更新了封装信息表.....	1
• Updated bootstrap capacitor recommendation from 470-nF to 10-nF.....	3
• Updated trademark information.....	10

Changes from Revision F (April 2013) to Revision G (June 2016)	Page
• 新增了 ESD 等级表、特性说明部分、器件功能模式、应用和实现部分、电源相关建议部分、布局部分、器件和文档支持部分以及机械、封装和可订购信息部分.....	1
• 删除了对计算机设计软件 LM267X Made Simple (6.0 版) 的所有引用.....	1

Changes from Revision E (April 2013) to Revision F (April 2013)	Page
• Added information relating to WEBENCH.....	13
• Changed layout of National Data Sheet to TI format.....	26
• Added information relating to WEBENCH.....	28

5 说明 (续)

其他特性包括在额定输入电压和输出负载条件下，确保具有 $\pm 1.5\%$ 的输出电压容差和 $\pm 10\%$ 的振荡器频率容差。还具有外部关断功能，待机电流典型值为 $50\ \mu\text{A}$ 。输出开关具备电流限制以及在故障状况下提供全面保护的热关断功能。

6 Pin Configuration and Functions

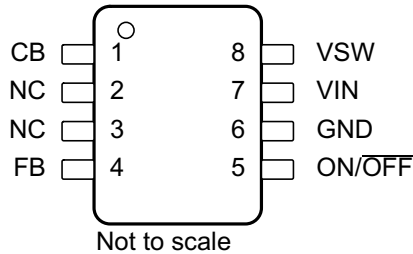
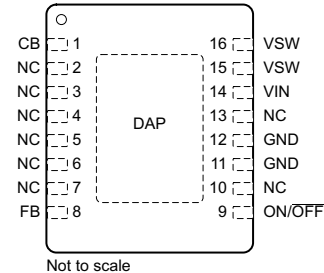


图 6-1. D or P Package 8-Pin SOIC or PDIP Top View



Connect DAP to pin 11 and 12.

图 6-2. NHN Package 16-Pin WSON Top View

表 6-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME	SOIC, PDIP	WSON		
CB	1	1	I	Bootstrap capacitor connection for high-side driver. Connect a high-quality, 10-nF capacitor from CB to VSW Pin.
FB	4	8	I	Feedback sense input pin. Connect to the midpoint of feedback divider to set VOUT for ADJ version or connect this pin directly to the output capacitor for a fixed output version.
ON/ OFF	5	9	I	Enable input to the voltage regulator. High = ON and low = OFF. Pull this pin high or float to enable the regulator
VSW	8	15, 16	O	Source pin of the internal high-side FET. This is a switching node. Attached this pin to an inductor and the cathode of the external diode
GND	6	11, 12	—	Power ground pins. Connect to system ground. Ground pins of C_{IN} and C_{OUT} . Path to C_{IN} must be as short as possible.
VIN	7	14	I	Supply input pin to collector pin of high-side FET. Connect to power supply and input bypass capacitors C_{IN} . Path from VIN pin to high frequency bypass C_{IN} and GND must be as short as possible.
NC	2, 3	2, 3, 4, 5, 6, 7, 10, 13	—	No connect pins

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

			MIN	MAX	UNIT
Supply voltage				45	V
ON/ OFF pin voltage, V _{SH}			– 0.1	6	V
Switch voltage to ground				– 1	V
Boost pin voltage				V _{SW} + 8	V
Feedback pin voltage, V _{FB}			– 0.3	14	V
Power dissipation			Internally Limited		
Lead temperature	D package	Vapor phase (60 s)	215		°C
		Infrared (15 s)	220		
	P package (soldering, 10 s)		260		
	WSO package		See AN-1187		
Maximum junction temperature				150	°C
Storage temperature, T _{stg}			– 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ^{(1) (2)}	±2000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) The human-body model is a 100-pF capacitor discharged through a 1.5-k Ω resistor into each pin.

7.3 Recommended Operating Conditions

			MIN	MAX	UNIT
Supply voltage			6.5	40	V
Junction temperature, T_J			– 40	125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LM2674			UNIT
		D (SOIC)	P (PDIP)	NHN (WSO)	
		8 PINS	8 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽²⁾	105	95	—	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.
- (2) Junction to ambient thermal resistance with approximately 1 square inch of printed-circuit board copper surrounding the leads. Additional copper area lowers thermal resistance further. The value $R_{\theta JA}$ for the WSO (NHN) package is specifically dependent on PCB trace area, trace material, and the number of layers and thermal vias. For improved thermal resistance and power dissipation for the WSO package, see [AN-1187 Leadless Leadframe Package \(LLP\)](#).

7.5 Electrical Characteristics - 3.3-V Version

$T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN ⁽³⁾	TYP ⁽²⁾	MAX ⁽³⁾	UNIT
SYSTEM PARAMETERS (see 图 9-1) ⁽¹⁾						
V _{OUT} Output voltage	V _{IN} = 8 V to 40 V, I _{LOAD} = 20 mA to 500 mA	T _J = 25°C	3.251	3.3	3.35	V
		T _J = - 40°C to 125°C	3.201		3.399	
	V _{IN} = 6.5 V to 40 V, I _{LOAD} = 20 mA to 250 mA	T _J = 25°C	3.251	3.3	3.35	
		T _J = - 40°C to 125°C	3.201		3.399	
η Efficiency	V _{IN} = 12 V, I _{LOAD} = 500 mA		86%			

- (1) External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2674 is used as shown in 图 9-1 and 图 9-5, system performance is as specified by the system parameters section of the Electrical Characteristics.
- (2) Typical numbers are at 25°C and represent the most likely norm.
- (3) All limits are used to calculate Average Outgoing Quality Level (AOQL).

7.6 Electrical Characteristics - 5-V Version

$T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN ⁽³⁾	TYP ⁽²⁾	MAX ⁽³⁾	UNIT
SYSTEM PARAMETERS (see 图 9-1) ⁽¹⁾						
V _{OUT} Output voltage	V _{IN} = 8 V to 40 V, I _{LOAD} = 20 mA to 500 mA	T _J = 25°C	4.925	5	5.075	V
		T _J = - 40°C to 125°C	4.85		5.15	
	V _{IN} = 6.5 V to 40 V, I _{LOAD} = 20 mA to 250 mA	T _J = 25°C	4.925	5	5.075	
		T _J = - 40°C to 125°C	4.85		5.15	
η Efficiency	V _{IN} = 12 V, I _{LOAD} = 500 mA		90%			

- (1) External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2674 is used as shown in 图 9-1 and 图 9-5, system performance is as specified by the system parameters section of the Electrical Characteristics.
- (2) Typical numbers are at 25°C and represent the most likely norm.
- (3) All limits are used to calculate Average Outgoing Quality Level (AOQL).

7.7 Electrical Characteristics - 12-V Version

$T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN ⁽³⁾	TYP ⁽²⁾	MAX ⁽³⁾	UNIT
SYSTEM PARAMETERS (see 图 9-1) ⁽¹⁾						
V _{OUT} Output voltage	V _{IN} = 15 V to 40 V, I _{LOAD} = 20 mA to 500 mA	T _J = 25°C	11.82	12	12.18	V
		T _J = - 40°C to 125°C	11.64		12.36	
η Efficiency	V _{IN} = 24 V, I _{LOAD} = 500 mA		94%			

- (1) External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2674 is used as shown in 图 9-1 and 图 9-5, system performance is as specified by the system parameters section of the Electrical Characteristics.
- (2) Typical numbers are at 25°C and represent the most likely norm.
- (3) All limits are used to calculate Average Outgoing Quality Level (AOQL).

7.8 Electrical Characteristics – Adjustable Voltage Version

$T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN ⁽³⁾	TYP ⁽²⁾	MAX ⁽³⁾	UNIT
SYSTEM PARAMETERS (see 图 9-5) ⁽¹⁾					
V_{FB} Feedback voltage	$V_{IN} = 8\text{ V to }40\text{ V}$, $I_{LOAD} = 20\text{ mA to }500\text{ mA}$, V_{OUT} programmed for 5 V (see 图 9-5)	$T_J = 25^\circ\text{C}$	1.192	1.21	1.228
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$	1.174		1.246
	$V_{IN} = 6.5\text{ V to }40\text{ V}$, $I_{LOAD} = 20\text{ mA to }250\text{ mA}$, V_{OUT} programmed for 5 V (see 图 9-5)	$T_J = 25^\circ\text{C}$	1.192	1.21	1.228
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$	1.174		1.246
η Efficiency	$V_{IN} = 12\text{ V}$, $I_{LOAD} = 500\text{ mA}$		90%		

- (1) External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2674 is used as shown in 图 9-1 and 图 9-5, system performance is as specified by the system parameters section of the Electrical Characteristics.
- (2) Typical numbers are at 25°C and represent the most likely norm.
- (3) All limits are used to calculate Average Outgoing Quality Level (AOQL).

7.9 Electrical Characteristics – All Output Voltage Versions

$T_J = 25^\circ\text{C}$, $V_{IN} = 12\text{ V}$ for the 3.3-V, 5-V, and adjustable versions and $V_{IN} = 24\text{ V}$ for the 12-V version, and $I_{LOAD} = 100\text{ mA}$ (unless otherwise noted)

PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DEVICE PARAMETERS					
I_Q Quiescent current	$V_{FEEDBACK} = 8\text{ V}$ for 3.3-V, 5-V, and adjustable voltage versions		2.5	3.6	mA
	$V_{FEEDBACK} = 15\text{ V}$ for 12-V versions		2.5		mA
I_{STBY} Standby quiescent current	ON/ $\overline{\text{OFF}}$ pin = 0 V	$T_J = 25^\circ\text{C}$	50	100	μA
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$		150	
I_{CL} Current limit	$T_J = 25^\circ\text{C}$	0.62	0.8	1.2	A
	$T_J = -40^\circ\text{C to }125^\circ\text{C}$	0.575		1.25	
I_L Output leakage current	$V_{IN} = 40\text{ V}$, ON/ $\overline{\text{OFF}}$ pin = 0 V, $V_{SWITCH} = 0\text{ V}$		1	25	μA
	$V_{SWITCH} = -1\text{ V}$, ON/ $\overline{\text{OFF}}$ pin = 0 V		6	15	mA
$R_{DS(ON)}$ Switch ON-resistance	$I_{SWITCH} = 500\text{ mA}$	$T_J = 25^\circ\text{C}$	0.25	0.4	Ω
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$		0.6	
f_O Oscillator frequency	Measured at switch pin	$T_J = 25^\circ\text{C}$	260		kHz
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$	225	275	
D	Maximum duty cycle		95%		
	Minimum duty cycle		0%		
I_{BIAS} Feedback bias current	$V_{FEEDBACK} = 1.3\text{ V}$ (adjustable version only)		85		nA
$V_{S/D}$ ON/ $\overline{\text{OFF}}$ pin voltage threshold	Turnon threshold, rising ⁽¹⁾	$T_J = 25^\circ\text{C}$	1.4		V
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$	0.8	2	
$I_{S/D}$ ON/ $\overline{\text{OFF}}$ pin current	ON/ $\overline{\text{OFF}}$ pin = 0 V	$T_J = 25^\circ\text{C}$	20		μA
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$	7	37	

- (1) The ON/ $\overline{\text{OFF}}$ pin is internally pulled up to 7 V and can be left floating for always-on operation.

7.10 Typical Characteristics

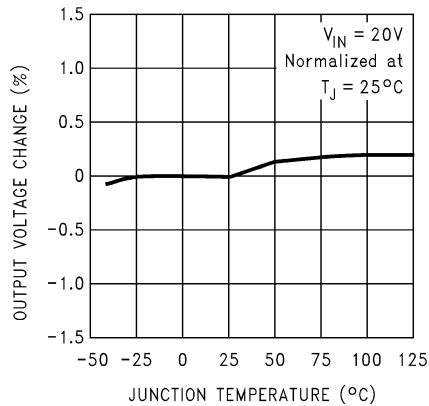


图 7-1. Normalized Output Voltage

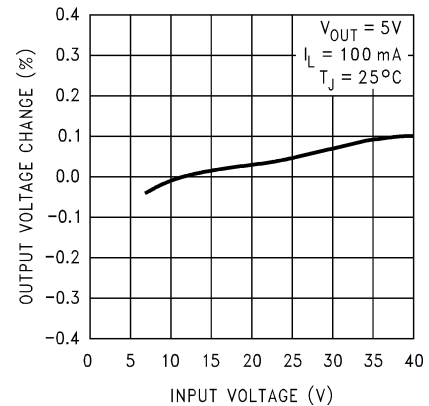


图 7-2. Line Regulation

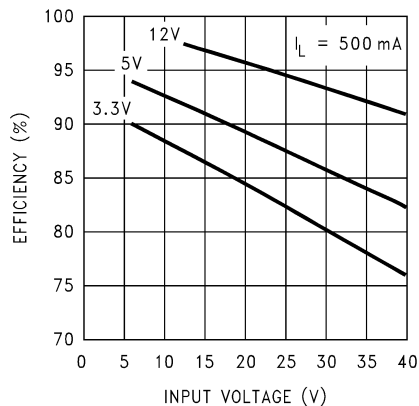


图 7-3. Efficiency

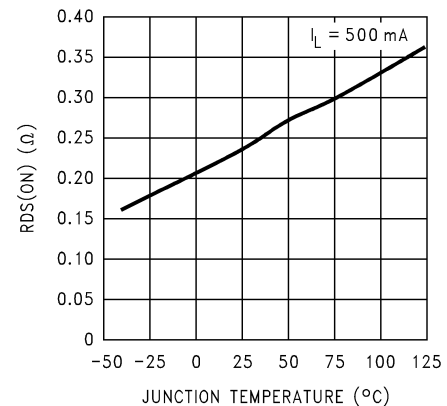


图 7-4. Drain-to-Source Resistance

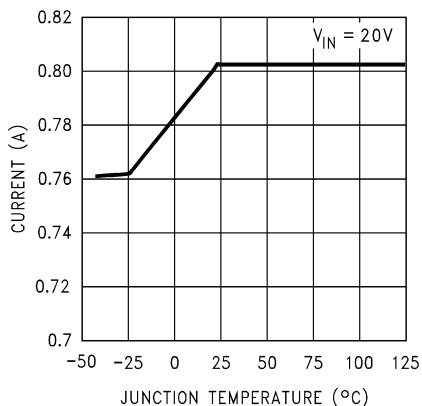


图 7-5. Switch Current Limit

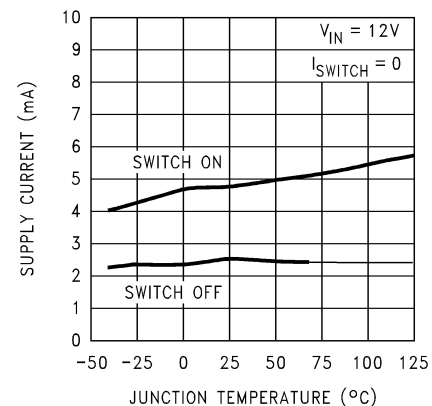


图 7-6. Operating Quiescent Current

7.10 Typical Characteristics (continued)

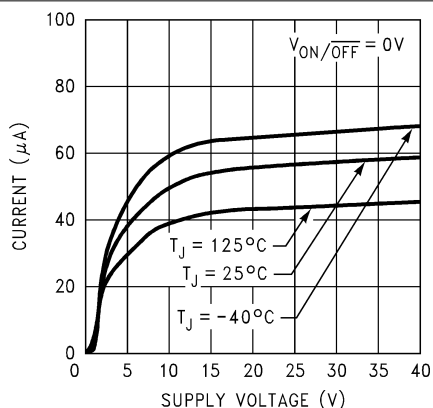


图 7-7. Standby Quiescent Current

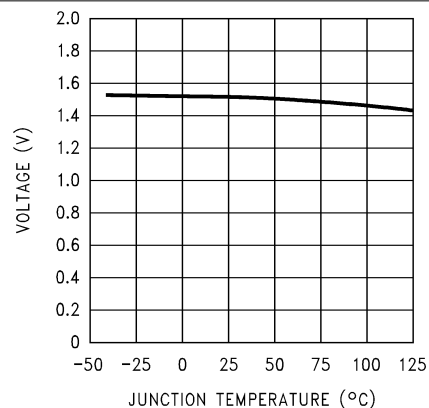


图 7-8. ON/ OFF Threshold Voltage

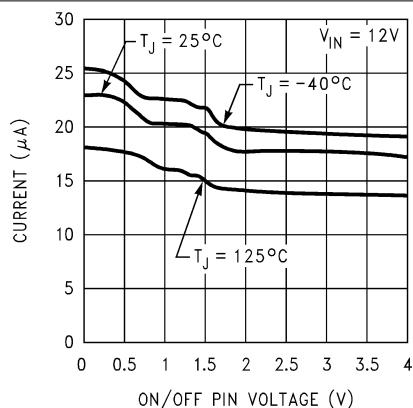


图 7-9. ON/ OFF Pin Current (Sourcing)

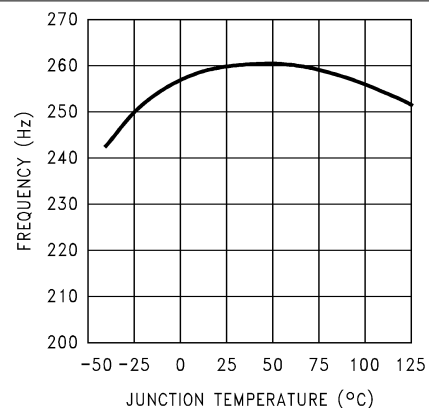


图 7-10. Switching Frequency

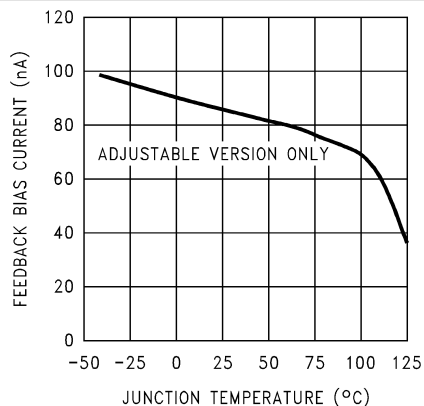


图 7-11. Feedback Pin Bias Current

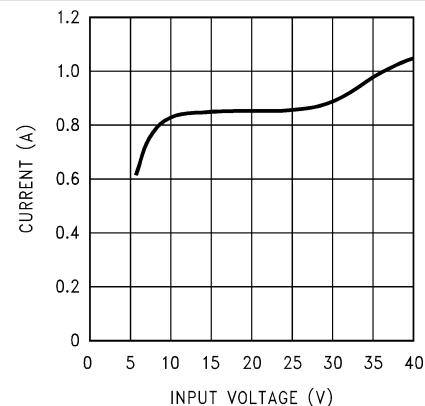


图 7-12. Peak Switch Current

7.10 Typical Characteristics (continued)

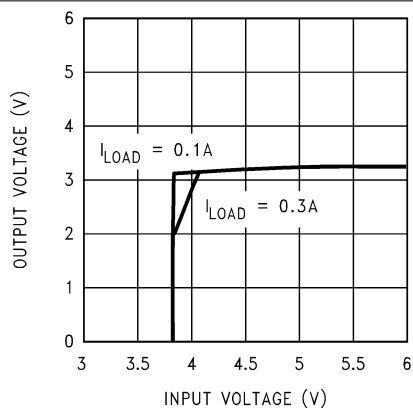


图 7-13. Dropout Voltage, 3.3-V Version

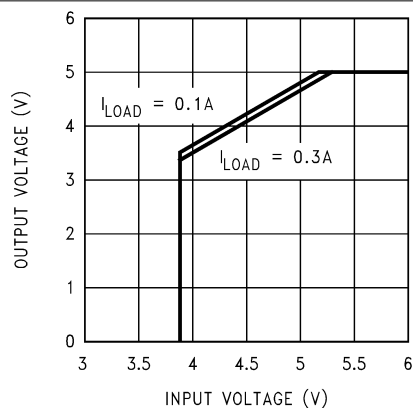


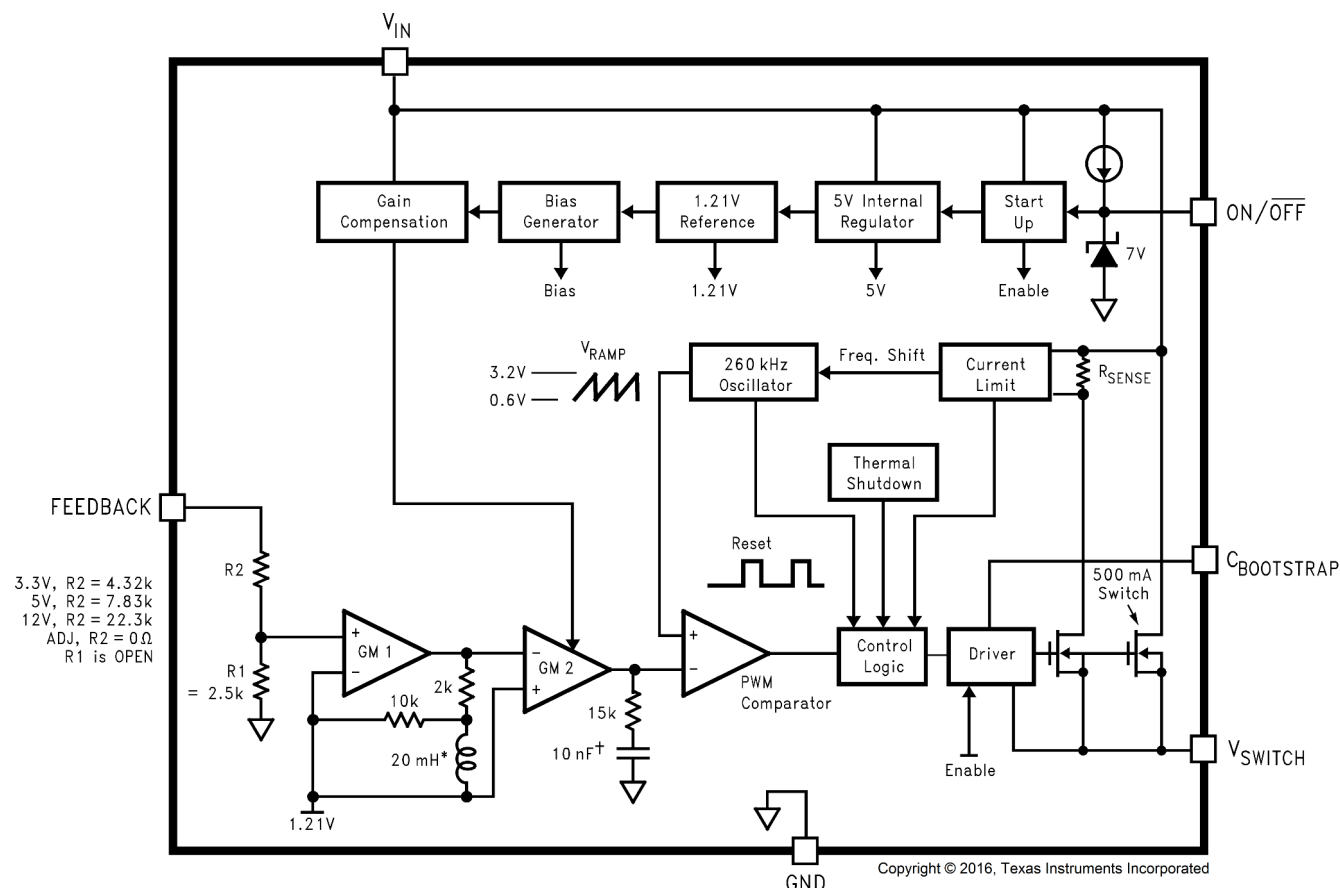
图 7-14. Dropout Voltage, 5-V Version

8 Detailed Description

8.1 Overview

The LM2674 SIMPLE SWITCHER® power converter regulator is an easy-to-use non-synchronous step-down DC-DC converter with a wide input voltage range up to 40 V. The LM2674 is capable of delivering up to 0.5-A DC load current with excellent line and load regulation. These devices are available in fixed output voltages of 3.3 V, 5 V, 12 V, and an adjustable output version. The family requires few external components and the pin arrangement was designed for simple, optimum PCB layout.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Adjustable Output Voltage

The voltage regulation loop in the LM2674 regulates output voltage by maintaining the voltage on FB pin (VFB) to be the same as the internal REF voltage (VREF). A resistor divider pair is required to program the ratio from output voltage VOUT to VFB. The resistor is connected from the VOUT of the LM2674 to ground with the mid-point connecting to the FB pin. The voltage reference system produces a precise voltage reference over temperature. The internal REF voltage is 1.21 V typically. To program the output voltage of the LM2674 to be a certain value VOUT, R1 can be calculated with a selected R2 (see [Adjustable Output Voltage Typical Application](#)). R2 is in the range from 10 kΩ to 100 kΩ is recommended for most applications. If the resistor divider is not connected properly, output voltage cannot be regulated because the feedback loop is broken. If the FB pin is shorted to ground, the output voltage is driven close to VIN, because the regulator sees very low voltage on the FB pin and tries to regulator it up. The load connected to the output can be damaged under such a condition. Do not short FB pin to ground when the LM2674 is enabled. It is important to route the feedback trace away from the noisy area of the PCB. For more layout recommendations, see [Layout](#).

8.4 Device Functional Modes

8.4.1 Shutdown Mode

The ON/ $\overline{\text{OFF}}$ pin provides electrical ON and OFF control for the LM2674. When the voltage of this pin is lower than 1.4 V, the device is in shutdown mode. The typical standby current in this mode is 50 μA .

8.4.2 Active Mode

When the voltage of the ON/OFF pin is higher than 1.4 V, the device starts switching and the output voltage rises until it reaches a normal regulation voltage.

9 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

9.1 Application Information

The LM2674 is a step-down DC-DC regulator. The LM2674 is typically used to convert a higher DC voltage to a lower DC voltage with a maximum output current of 0.5 A. The following design procedure can be used to select components for the LM2674. Alternately, the WEBENCH® software can be used to generate complete designs. When generating a design, the WEBENCH software uses iterative design procedure and accesses comprehensive databases of components. See ti.com for more details.

When the output voltage is greater than approximately 6 V, and the duty cycle at minimum input voltage is greater than approximately 50%, the designer must exercise caution in selection of the output filter components. When an application designed to these specific operating conditions is subjected to a current limit fault condition, observing a large hysteresis in the current limit is possible. This can affect the output voltage of the device until the load current is reduced sufficiently to allow the current limit protection circuit to reset itself.

Under current limiting conditions, the LM267x is designed to respond in the following manner:

1. At the moment when the inductor current reaches the current limit threshold, the ON-pulse is immediately terminated. This happens for any application condition.
2. However, the current limit block is also designed to momentarily reduce the duty cycle to below 50% to avoid subharmonic oscillations, which can cause the inductor to saturate.
3. Thereafter, after the inductor current falls below the current limit threshold, there is a small relaxation time during which the duty cycle progressively rises back above 50% to the value required to achieve regulation.

If the output capacitance is sufficiently *large*, as the output tries to recover, the output capacitor charging current can be large enough to repeatedly re-trigger the current limit circuit before the output has fully settled. This condition is exacerbated with higher output voltage settings because the energy requirement of the output capacitor varies as the square of the output voltage ($\frac{1}{2} CV^2$), thus requiring an increased charging current. A simple test to determine if this condition can exist for a suspect application is to apply a short circuit across the output of the converter, and then remove the shorted output condition. In an application with properly selected external components, the output recovers smoothly. Practical values of external components that have been experimentally found to work well under these specific operating conditions are $C_{OUT} = 47 \mu F$, $L = 22 \mu H$.

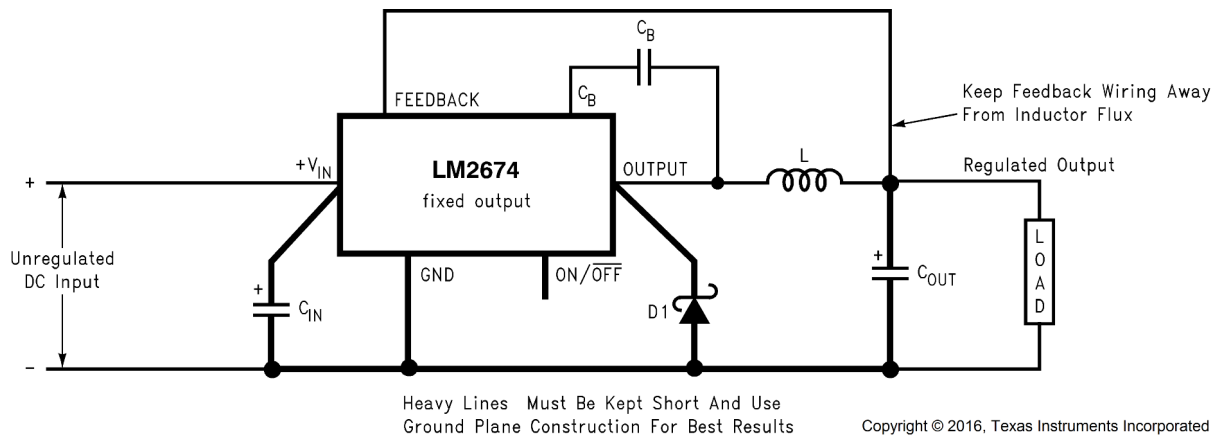
备注

Even with these components, for a device current limit of ICLIM, the maximum load current under which the possibility of the large current limit hysteresis can be minimized is ICLIM/2.

For example, if the input is 24 V and the set output voltage is 18 V, then for a desired maximum current of 1.5 A, the current limit of the chosen switcher must be confirmed to be at least 3 A. Under extreme overcurrent or short-circuit conditions, the LM267X employs frequency foldback in addition to the current limit. If the cycle-by-cycle inductor current increases above the current limit threshold (due to short circuit or inductor saturation for example) the switching frequency is automatically reduced to protect the IC. Frequency below 100 kHz is typical for an extreme short-circuit condition.

9.2 Typical Applications

9.2.1 Fixed Output Voltage Typical Application



C_{IN} = 22- μ F, 50-V Tantalum, Sprague 199D Series
 C_{OUT} = 47- μ F, 25-V Tantalum, Sprague 595D Series
D1 = 3.3-A, 50-V Schottky Rectifier, IR 30WQ05F
L1 = 68- μ H Sumida #RCR110D-680L
 C_B = 0.01- μ F, 50-V Ceramic

图 9-1. Fixed Output Voltage Version

9.2.1.1 Design Requirements

表 9-1 lists the design parameters of this example.

表 9-1. Design Parameters

PARAMETER	VALUE
Regulated output voltage (3.3 V, 5 V, or 12 V), V_{OUT}	5 V
Maximum DC input voltage, $V_{IN(max)}$	12 V
Maximum load current, $I_{LOAD(max)}$	500 mA

9.2.1.2 Detailed Design Procedure

9.2.1.2.1 Custom Design with WEBENCH® Tools

[Click here](#) to create a custom design using the LM2674 devices with the WEBENCH Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

9.2.1.2.2 Inductor Selection (L1)

1. Select the correct inductor value selection guide from 图 9-10, 图 9-11, or 图 9-12 (output voltages of 3.3 V, 5 V, or 12 V respectively). For all other voltages, see the design procedure for the adjustable version. Use the inductor selection guide for the 5-V version shown in 图 9-11.
2. From the inductor value selection guide, identify the inductance region intersected by the maximum input voltage line and the maximum load current line. Each region is identified by an inductance value and an inductor code (LXX). From the inductor value selection guide shown in 图 9-11, the inductance region intersected by the 12-V horizontal line and the 500-mA vertical line is 47 μ H, and the inductor code is L13.
3. Select an appropriate inductor from the four manufacturer's part numbers listed in 表 9-7. Each manufacturer makes a different style of inductor to allow flexibility in meeting various design requirements. Listed below are some of the differentiating characteristics of each manufacturer's inductors:
 - *Schott*: ferrite EP core inductors; these have very low leakage magnetic fields to reduce electro-magnetic interference (EMI) and are the lowest power loss inductors
 - *Renco*: ferrite stick core inductors; benefits are typically lowest cost inductors and can withstand E•T and transient peak currents above rated values. Be aware that these inductors have an external magnetic field which can generate more EMI than other types of inductors.
 - *Pulse*: powdered iron toroid core inductors; these can also be low cost and can withstand larger than normal E•T and transient peak currents. Toroid inductors have low EMI.
 - *Coilcraft*: ferrite drum core inductors; these are the smallest physical size inductors, available only as SMT components. Be aware that these inductors also generate EMI—but less than stick inductors.

Complete specifications for these inductors are available from the respective manufacturers. The inductance value required is 47 μ H. From 表 9-7, go to the L13 line and choose an inductor part number from any of the four manufacturers shown. (In most instances, both through hole and surface mount inductors are available).

9.2.1.2.3 Output Capacitor Selection (C_{OUT})

Select an output capacitor from the output capacitor 表 9-2. Using the output voltage and the inductance value found in the inductor selection guide, step 1, locate the appropriate capacitor value and voltage rating. Use the 5-V section in the output capacitor 表 9-2. Choose a capacitor value and voltage rating from the line that contains the inductance value of 47 μ H. The capacitance and voltage rating values corresponding to the 47- μ H inductor are the following:

- Surface mount
 - 68- μ F, 10-V Sprague 594D series
 - 100- μ F, 10-V AVX TPS series
- Through hole
 - 68- μ F, 10-V Sanyo OS-CON SA series
 - 150- μ F, 35-V Sanyo MV-GX series
 - 150- μ F, 35-V Nichicon PL series
 - 150- μ F, 35-V Panasonic HFQ series

The capacitor list contains through-hole electrolytic capacitors from four different capacitor manufacturers and surface-mount tantalum capacitors from two different capacitor manufacturers. TI recommends that both the manufacturers and the manufacturer's series that are listed in the table be used.

表 9-2. Output Capacitor Table

OUTPUT VOLTAGE (V)	INDUCTANCE (μ H)	OUTPUT CAPACITOR					
		SURFACE MOUNT		THROUGH HOLE			
		SPRAGUE 594D SERIES (μ F/V)	AVX TPS SERIES (μ F/V)	SANYO OS-CON SA SERIES (μ F/V)	SANYO MV-GX SERIES (μ F/V)	NICHICON PL SERIES (μ F/V)	PANASONIC HFQ SERIES (μ F/V)
3.3	22	120/6.3	100/10	100/10	330/35	330/35	330/35
	33	120/6.3	100/10	68/10	220/35	220/35	220/35
	47	68/10	100/10	68/10	150/35	150/35	150/35
	68	120/6.3	100/10	100/10	120/35	120/35	120/35
	100	120/6.3	100/10	100/10	120/35	120/35	120/35
	150	120/6.3	100/10	100/10	120/35	120/35	120/35
5	22	100/16	100/10	100/10	330/35	330/35	330/35
	33	68/10	100/10	68/10	220/35	220/35	220/35
	47	68/10	100/10	68/10	150/35	150/35	150/35
	68	100/16	100/10	100/10	120/35	120/35	120/35
	100	100/16	100/10	100/10	120/35	120/35	120/35
	150	100/16	100/10	100/10	120/35	120/35	120/35
12	22	120/20	(2 $\times$) 68/20	68/20	330/35	330/35	330/35
	33	68/25	68/20	68/20	220/35	220/35	220/35
	47	47/20	68/20	47/20	150/35	150/35	150/35
	68	47/20	68/20	47/20	120/35	120/35	120/35
	100	47/20	68/20	47/20	120/35	120/35	120/35
	150	47/20	68/20	47/20	120/35	120/35	120/35
	220	47/20	68/20	47/20	120/35	120/35	120/35

9.2.1.2.4 Catch Diode Selection (D1)

- In normal operation, the average current of the catch diode is the load current times the catch diode duty cycle, 1-D (D is the switch duty cycle, which is approximately the output voltage divided by the input voltage). The largest value of the catch diode average current occurs at the maximum load current and maximum input voltage (minimum D). For normal operation, the catch diode current rating must be at least 1.3 times greater than its maximum average current. However, if the power supply design must withstand a continuous output short, the diode must have a current rating equal to the maximum current limit of the LM2674. The most stressful condition for this diode is a shorted output condition. Refer to 表 9-3. In this example, a 1-A, 20-V Schottky diode provides the best performance. If the circuit must withstand a continuous shorted output, TI recommends a higher current Schottky diode.

表 9-3. Schottky Diode Selection Table

V_R	500-mA DIODES		3-A DIODES	
	SURFACE MOUNT	THROUGH- HOLE	SURFACE MOUNT	THROUGH- HOLE
20V	SK12	1N5817	SK32	1N5820
	B120	SR102		SR302
30V	SK13	1N5818	SK33	1N5821
	B130	11DQ03	30WQ03F	31DQ03
	MBRS130	SR103		

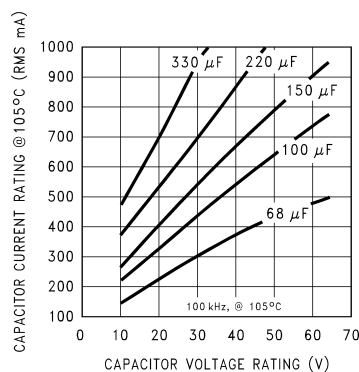
表 9-3. Schottky Diode Selection Table (continued)

V_R	500-mA DIODES		3-A DIODES	
	SURFACE MOUNT	THROUGH-HOLE	SURFACE MOUNT	THROUGH-HOLE
40V	SK14	1N5819	SK34	1N5822
	B140	11DQ04	30BQ040	MBR340
	MBRS140	SR104	30WQ04F	31DQ04
	10BQ040		MBRS340	SR304
	10MQ040		MBRD340	
	15MQ040			
50V	SK15	MBR150	SK35	MBR350
	B150	11DQ05	30WQ05F	31DQ05
	10BQ050	SR105		SR305

- The reverse voltage rating of the diode must be at least 1.25 times the maximum input voltage.
- Because of their fast switching speed and low forward voltage drop, Schottky diodes provide the best performance and efficiency. This Schottky diode must be placed close to the LM2674 using short leads and short printed-circuit traces.

9.2.1.2.5 Input Capacitor (C_{IN})

A low ESR aluminum or tantalum bypass capacitor is required between the input pin and ground to prevent large voltage transients from appearing at the input. This capacitor must be placed close to the IC using short leads. In addition, the RMS current rating of the input capacitor must be selected to be at least $\frac{1}{2}$ the DC load current. The capacitor manufacturer data sheet must be checked to assure that this current rating is not exceeded. The curves shown in 图 9-2 show typical RMS current ratings for several different aluminum electrolytic capacitor values. A parallel connection of two or more capacitors can be required to increase the total minimum RMS current rating to suit the application requirements.

**图 9-2. RMS Current Ratings for Low ESR Electrolytic Capacitors (Typical)**

For an aluminum electrolytic capacitor, the voltage rating must be at least 1.25 times the maximum input voltage. Caution must be exercised if solid tantalum capacitors are used. The tantalum capacitor voltage rating must be twice the maximum input voltage. 表 9-4 和 表 9-5 show the recommended application voltage for AVX TPS and Sprague 594D tantalum capacitors. TI recommends that they be surge current tested by the manufacturer. The TPS series available from AVX, and the 593D and 594D series from Sprague are all surge current tested. Another approach to minimize the surge current stresses on the input capacitor is to add a small inductor in series with the input supply line.

表 9-4. AVX TPS

RECOMMENDED APPLICATION VOLTAGE ⁽¹⁾	VOLTAGE RATING
85°C RATING	
3.3	6.3
5	10
10	20
12	25
15	35

表 9-5. Sprague 594D

RECOMMENDED APPLICATION VOLTAGE ⁽¹⁾	VOLTAGE RATING
85°C RATING	
2.5	4
3.3	6.3
5	10
8	16
12	20
18	25
24	35
29	50

(1) Recommended Application Voltage for AVX TPS and Sprague 594D Tantalum Chip Capacitors Derated for 85°C

Use caution when using only ceramic capacitors for input bypassing, because it can cause severe ringing at the V_{IN} pin. The important parameters for the input capacitor are the input voltage rating and the RMS current rating. With a maximum input voltage of 12 V, an aluminum electrolytic capacitor with a voltage rating greater than 15 V ($1.25 \times V_{IN}$) is required. The next higher capacitor voltage rating is 16 V.

The RMS current rating requirement for the input capacitor in a buck regulator is approximately $\frac{1}{2}$ the DC load current. In this example, with a 500-mA load, a capacitor with an RMS current rating of at least 250 mA is required. The curves shown in 图 9-2 can be used to select an appropriate input capacitor. From the curves, locate the 16-V line and note which capacitor values have RMS current ratings greater than 250 mA.

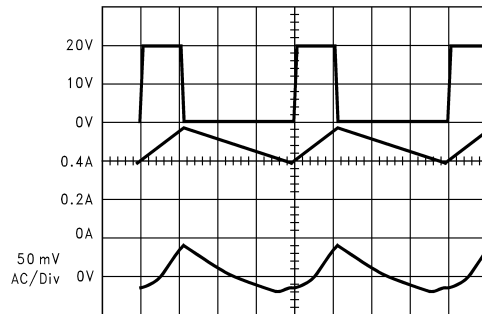
For a through-hole design, a 100- μ F, 16-V electrolytic capacitor (Panasonic HFQ series, Nichicon PL, Sanyo MV-GX series or equivalent) is adequate. Other types or other manufacturers' capacitors can be used provided the RMS ripple current ratings are adequate. Additionally, for a complete surface mount design, electrolytic capacitors such as the Sanyo CV-C or CV-BS and the Nichicon WF or UR and the NIC Components NACZ series can be considered.

For surface mount designs, solid tantalum capacitors can be used, but caution must be exercised with regard to the capacitor surge current rating and voltage rating. In this example, checking 表 9-4, and the Sprague 594D series datasheet, a Sprague 594D 15- μ F, 25-V capacitor is adequate.

9.2.1.2.6 Boost Capacitor (C_B)

This capacitor develops the necessary voltage to turn the switch gate on fully. All applications must use a 0.01- μ F, 50-V ceramic capacitor. For this application, and all applications, use a 0.01- μ F, 50-V ceramic capacitor.

9.2.1.3 Application Curves



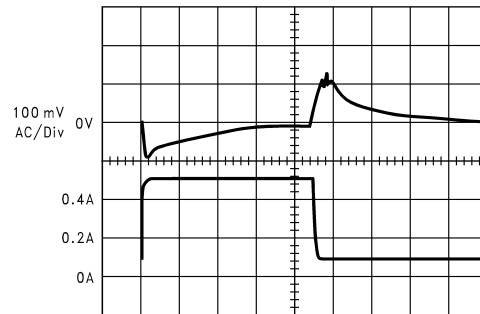
Continuous mode switching waveforms $V_{IN} = 20\text{ V}$, $V_{OUT} = 5\text{ V}$, $I_{LOAD} = 500\text{ mA}$, $L = 100\text{ }\mu\text{H}$, $C_{OUT} = 100\text{ }\mu\text{F}$, $C_{OUT}ESR = 0.1\text{ }\Omega$

A: V_{SW} pin voltage = 10 V/div

B: Inductor current = 0.2 A/div

C: Output ripple voltage = 50 mV/div ac-coupled

图 9-3. Horizontal Time Base: 1 $\mu\text{s}/\text{div}$



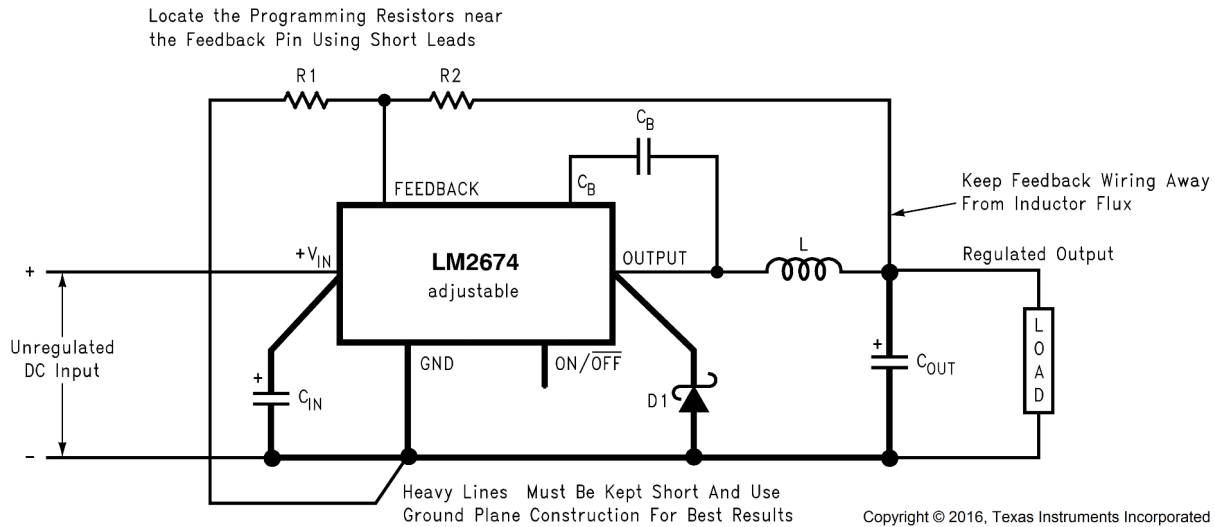
Load transient response for continuous mode $V_{IN} = 20\text{ V}$, $V_{OUT} = 5\text{ V}$, $L = 100\text{ }\mu\text{H}$, $C_{OUT} = 100\text{ }\mu\text{F}$, $C_{OUT}ESR = 0.1\text{ }\Omega$

A: Output voltage = 100 mV/div, ac-coupled

B: Load current = 100-mA to 500-mA load pulse

图 9-4. Horizontal Time Base: 50 $\mu\text{s}/\text{div}$

9.2.2 Adjustable Output Voltage Typical Application



$C_{IN} = 22\text{-}\mu\text{F}$, 50-V Tantalum, Sprague 199D Series

$C_{OUT} = 47\text{-}\mu\text{F}$, 25-V Tantalum, Sprague 595D Series

D1 = 3.3-A, 50-V Schottky Rectifier, IR 30WQ05F

L1 = 68- μH Sumida #RCR110D-680L

$R_1 = 1.5\text{ k}\Omega$, 1%

$C_B = 0.01\text{-}\mu\text{F}$, 50-V Ceramic

For a 5-V output, select R_2 to be 4.75 k Ω , 1%

$$V_{OUT} = V_{REF} \left(1 + \frac{R_2}{R_1} \right)$$

where $V_{REF} = 1.21\text{ V}$

$$R_2 = R_1 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right)$$

Use a 1% resistor for best stability.

图 9-5. Adjustable Output Voltage Version

9.2.2.1 Design Requirements

表 9-6 lists the design parameters of this example.

表 9-6. Design Parameters

PARAMETER	VALUE
Regulated output voltage, V_{OUT}	20
Maximum input voltage, $V_{IN(max)}$	28
Maximum load current, $I_{LOAD(max)}$	500
Switching frequency, F	Fixed at a nominal 260 kHz

9.2.2.2 Detailed Design Procedure

9.2.2.2.1 Programming Output Voltage

Select R_1 and R_2 , as shown in 图 9-5.

Use the following formula to select the appropriate resistor values.

$$V_{OUT} = V_{REF} \left(1 + \frac{R_2}{R_1} \right) \quad (1)$$

where

- $V_{REF} = 1.21 \text{ V}$

Select a value for R_1 between $240 \text{ } \Omega$ and $1.5 \text{ k}\Omega$. The lower resistor values minimize noise pickup in the sensitive feedback pin. (For the lowest temperature coefficient and the best stability with time, use 1% metal film resistors.)

$$R_2 = R_1 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right) \quad (2)$$

Select R_1 to be $1 \text{ k}\Omega$, 1%. Solve for R_2 .

$$R_2 = R_1 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right) = 1 \text{ k}\Omega \left(\frac{20 \text{ V}}{1.23 \text{ V}} - 1 \right) \quad (3)$$

where

- $R_2 = 1 \text{ k} (16.53 - 1) = 15.53 \text{ k}\Omega$, closest 1% value is $15.4 \text{ k}\Omega$
 $R_2 = 15.4 \text{ k}\Omega$

9.2.2.2.2 Inductor Selection (L1)

1. Calculate the inductor Volt • microsecond constant $E \cdot T$ ($\text{V} \cdot \mu\text{s}$) from 方程式 4.

$$E \cdot T = (V_{IN(MAX)} - V_{OUT} - V_{SAT}) \cdot \frac{V_{OUT} + V_D}{V_{IN(MAX)} - V_{SAT} + V_D} \cdot \frac{1000}{260} (\text{V} \cdot \mu\text{s}) \quad (4)$$

where

- V_{SAT} = internal switch saturation voltage = 0.25 V
- V_D = diode forward voltage drop = 0.5 V

Calculate the inductor Volt • microsecond constant ($E \cdot T$) with 方程式 5.

$$\begin{aligned} E \cdot T &= (28 - 20 - 0.25) \cdot \frac{20 + 0.5}{28 - 0.25 + 0.5} \cdot \frac{1000}{260} (\text{V} \cdot \mu\text{s}) \\ E \cdot T &= (7.75) \cdot \frac{20.5}{28.25} \cdot 3.85 (\text{V} \cdot \mu\text{s}) = 21.6 (\text{V} \cdot \mu\text{s}) \end{aligned} \quad (5)$$

2. Use the $E \cdot T$ value from the previous formula and match it with the $E \cdot T$ number on the vertical axis of the inductor value selection guide shown in 图 9-13.

$$E \cdot T = 21.6 (\text{V} \cdot \mu\text{s})$$

3. On the horizontal axis, select the maximum load current.

$$I_{LOAD(max)} = 500 \text{ mA}$$

4. Identify the inductance region intersected by the $E \cdot T$ value and the maximum load current value. Each region is identified by an inductance value and an inductor code (LXX).

From the inductor value selection guide shown in 图 9-13, the inductance region intersected by the $21.6 (\text{V} \cdot \mu\text{s})$ horizontal line and the 500-mA vertical line is $100 \text{ } \mu\text{H}$, and the inductor code is L20.

5. Select an appropriate inductor from the four manufacturer's part numbers listed in 表 9-7. For information on the different types of inductors, see the inductor selection in the fixed output voltage design procedure.

From 表 9-7, locate line L20, and select an inductor part number from the list of manufacturers' part numbers.

表 9-7. Inductor Manufacturers' Part Numbers

IND. REF. DESG.	INDUCTANCE (μ H)	CURRENT (A)	SCHOTT		RENCO		PULSE ENGINEERING		COILCRAFT
			THROUGH HOLE	SURFACE MOUNT	THROUGH HOLE	SURFACE MOUNT	THROUGH HOLE	SURFACE MOUNT	SURFACE MOUNT
L2	150	0.21	67143920	67144290	RL-5470-4	RL1500-150	PE-53802	PE-53802-S	DO1608-154
L3	100	0.26	67143930	67144300	RL-5470-5	RL1500-100	PE-53803	PE-53803-S	DO1608-104
L4	68	0.32	67143940	67144310	RL-1284-68-43	RL1500-68	PE-53804	PE-53804-S	DO1608-683
L5	47	0.37	67148310	67148420	RL-1284-47-43	RL1500-47	PE-53805	PE-53805-S	DO1608-473
L6	33	0.44	67148320	67148430	RL-1284-33-43	RL1500-33	PE-53806	PE-53806-S	DO1608-333
L7	22	0.52	67148330	67148440	RL-1284-22-43	RL1500-22	PE-53807	PE-53807-S	DO1608-223
L9	220	0.32	67143960	67144330	RL-5470-3	RL1500-220	PE-53809	PE-53809-S	DO3308-224
L10	150	0.39	67143970	67144340	RL-5470-4	RL1500-150	PE-53810	PE-53810-S	DO3308-154
L11	100	0.48	67143980	67144350	RL-5470-5	RL1500-100	PE-53811	PE-53811-S	DO3308-104
L12	68	0.58	67143990	67144360	RL-5470-6	RL1500-68	PE-53812	PE-53812-S	DO3308-683
L13	47	0.7	67144000	67144380	RL-5470-7	RL1500-47	PE-53813	PE-53813-S	DO3308-473
L14	33	0.83	67148340	67148450	RL-1284-33-43	RL1500-33	PE-53814	PE-53814-S	DO3308-333
L15	22	0.99	67148350	67148460	RL-1284-22-43	RL1500-22	PE-53815	PE-53815-S	DO3308-223
L18	220	0.55	67144040	67144420	RL-5471-2	RL1500-220	PE-53818	PE-53818-S	DO3316-224
L19	150	0.66	67144050	67144430	RL-5471-3	RL1500-150	PE-53819	PE-53819-S	DO3316-154
L20	100	0.82	67144060	67144440	RL-5471-4	RL1500-100	PE-53820	PE-53820-S	DO3316-104
L21	68	0.99	67144070	67144450	RL-5471-5	RL1500-68	PE-53821	PE-53821-S	DO3316-683

9.2.2.2.3 Output Capacitor Selection (C_{OUT})

- Select an output capacitor from the capacitor code selection guide in 表 9-8. Using the inductance value found in the inductor selection guide, step 1, locate the appropriate capacitor code corresponding to the desired output voltage. Use the appropriate row of the capacitor code selection guide, in 表 9-8. For this example, use the 15-V to 20-V row. The capacitor code corresponding to an inductance of 100 μ H is C20.
- Select an appropriate capacitor value and voltage rating, using the capacitor code, from the output capacitor selection in 表 9-9. There are two solid tantalum (surface-mount) capacitor manufacturers and four electrolytic (through-hole) capacitor manufacturers to choose from. TI recommends that both the manufacturers and the manufacturer's series that are listed in the table be used. From the output capacitor selection in 表 9-9, choose a capacitor value (and voltage rating) that intersects the capacitor code(s) selected in section A, C20.

The capacitance and voltage rating values corresponding to the capacitor code C20 are the following:

- Surface mount
 - 33- μ F, 25-V Sprague 594D series
 - 33- μ F, 25-V AVX TPS series
- Through hole
 - 33- μ F, 25-V Sanyo OS-CON SC series
 - 120- μ F, 35-V Sanyo MV-GX series
 - 120- μ F, 35-V Nichicon PL series
 - 20- μ F, 35-V Panasonic HFQ series

Other manufacturers or other types of capacitors can also be used, provided the capacitor specifications (especially the 100-kHz ESR) closely match the characteristics of the capacitors listed in the output capacitor table. Refer to the capacitor manufacturers' data sheet for this information.

表 9-8. Capacitor Code Selection Guide

CASE STYLE ⁽¹⁾	OUTPUT VOLTAGE (V)	INDUCTANCE (μ H)						
		22	33	47	68	100	150	220
SM and TH	1.21 - 2.5	—	—	—	—	C1	C2	C3

表 9-8. Capacitor Code Selection Guide (continued)

CASE STYLE ⁽¹⁾	OUTPUT VOLTAGE (V)	INDUCTANCE (μH)						
		22	33	47	68	100	150	220
SM and TH	2.5 - 3.75	—	—	—	C1	C2	C3	C3
SM and TH	3.75 - 5	—	—	C4	C5	C6	C6	C6
SM and TH	5 - 6.25	—	C4	C7	C6	C6	C6	C6
SM and TH	6.25 - 7.5	C8	C4	C7	C6	C6	C6	C6
SM and TH	7.5 - 10	C9	C10	C11	C12	C13	C13	C13
SM and TH	10 - 12.5	C14	C11	C12	C12	C13	C13	C13
SM and TH	12.5 - 15	C15	C16	C17	C17	C17	C17	C17
SM and TH	15 - 20	C18	C19	C20	C20	C20	C20	C20
SM and TH	20 - 30	C21	C22	C22	C22	C22	C22	C22
TH	30 - 37	C23	C24	C24	C25	C25	C25	C25

(1) SM = Surface mount and TH = Through hole

表 9-9. Output Capacitor Selection Table

OUTPUT CAPACITOR						
CAP. REF. DESG. #	SURFACE MOUNT		THROUGH HOLE			
	SPRAGUE 594D SERIES (μF/V)	AVX TPS SERIES (μF/V)	SANYO OS-CON SA SERIES (μF/V)	SANYO MV-GX SERIES (μF/V)	NICHICON PL SERIES (μF/V)	PANASONIC HFQ SERIES (μF/V)
C1	120/6.3	100/10	100/10	220/35	220/35	220/35
C2	120/6.3	100/10	100/10	150/35	150/35	150/35
C3	120/6.3	100/10	100/35	120/35	120/35	120/35
C4	68/10	100/10	68/10	220/35	220/35	220/35
C5	100/16	100/10	100/10	150/35	150/35	150/35
C6	100/16	100/10	100/10	120/35	120/35	120/35
C7	68/10	100/10	68/10	150/35	150/35	150/35
C8	100/16	100/10	100/10	330/35	330/35	330/35
C9	100/16	100/16	100/16	330/35	330/35	330/35
C10	100/16	100/16	68/16	220/35	220/35	220/35
C11	100/16	100/16	68/16	150/35	150/35	150/35
C12	100/16	100/16	68/16	120/35	120/35	120/35
C13	100/16	100/16	100/16	120/35	120/35	120/35
C14	100/16	100/16	100/16	220/35	220/35	220/35
C15	47/20	68/20	47/20	220/35	220/35	220/35
C16	47/20	68/20	47/20	150/35	150/35	150/35
C17	47/20	68/20	47/20	120/35	120/35	120/35
C18	68/25	(2×) 33/25	47/ ⁽¹⁾	220/35	220/35	220/35
C19	33/25	33/25	33/25 ⁽¹⁾	150/35	150/35	150/35
C20	33/25	33/25	33/25 ⁽¹⁾	120/35	120/35	120/35
C21	33/35	(2×) 22/25	See ⁽²⁾	150/35	150/35	150/35
C22	33/35	22/35	See ⁽²⁾	120/35	120/35	120/35
C23	See ⁽²⁾	See ⁽²⁾	See ⁽²⁾	220/50	100/50	120/50
C24	See ⁽²⁾	See ⁽²⁾	See ⁽²⁾	150/50	100/50	120/50
C25	See ⁽²⁾	See ⁽²⁾	See ⁽²⁾	150/50	82/50	82/50

(1) The SC series of Os-Con capacitors (others are SA series)

(2) The voltage ratings of the surface mount tantalum chip and Os-Con capacitors are too low to work at these voltages.

9.2.2.2.4 Catch Diode Selection (D1)

1. In normal operation, the average current of the catch diode is the load current times the catch diode duty cycle, $1-D$ (D is the switch duty cycle, which is approximately V_{OUT}/V_{IN}). The largest value of the catch diode average current occurs at the maximum input voltage (minimum D). For normal operation, the catch diode current rating must be at least 1.3 times greater than its maximum average current. However, if the power supply design must withstand a continuous output short, the diode must have a current rating greater than the maximum current limit of the LM2674. The most stressful condition for this diode is a shorted output condition. Schottky diodes provide the best performance, and in this example a 500-mA, 40-V Schottky diode is a good choice. If the circuit must withstand a continuous shorted output, TI recommends a higher current (at least 1.2 A) Schottky diode.
2. The reverse voltage rating of the diode must be at least 1.25 times the maximum input voltage.
3. Because of their fast switching speed and low forward voltage drop, Schottky diodes provide the best performance and efficiency. The Schottky diode must be placed close to the LM2674 using short leads and short printed-circuit traces.

9.2.2.2.5 Input Capacitor (C_{IN})

A low ESR aluminum or tantalum bypass capacitor is required between the input pin and ground to prevent large voltage transients from appearing at the input. This capacitor must be placed close to the IC using short leads. In addition, the RMS current rating of the input capacitor must be selected to be at least $\frac{1}{2}$ the DC load current. The capacitor manufacturer data sheet must be checked to assure that this current rating is not exceeded. The curves shown in 图 9-2 show typical RMS current ratings for several different aluminum electrolytic capacitor values. A parallel connection of two or more capacitors can be required to increase the total minimum RMS current rating to suit the application requirements.

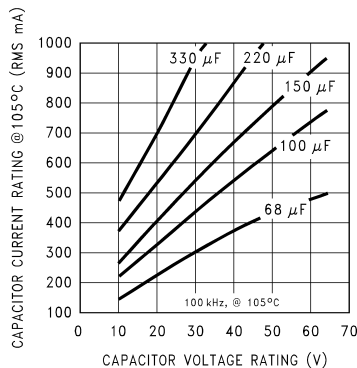


图 9-6. RMS Current Ratings for Low ESR Electrolytic Capacitors (Typical)

For an aluminum electrolytic capacitor, the voltage rating must be at least 1.25 times the maximum input voltage. Caution must be exercised if solid tantalum capacitors are used. The tantalum capacitor voltage rating must be twice the maximum input voltage. 表 9-10 and 表 9-5 show the recommended application voltage for AVX TPS and Sprague 594D tantalum capacitors. TI also recommends that they be surge current tested by the manufacturer. The TPS series available from AVX, and the 593D and 594D series from Sprague are all surge current tested. Another approach to minimize the surge current stresses on the input capacitor is to add a small inductor in series with the input supply line.

表 9-10. AVX TPS

RECOMMENDED APPLICATION VOLTAGE ⁽¹⁾	VOLTAGE RATING
85°C RATING	
3.3	6.3
5	10
10	20

表 9-10. AVX TPS (continued)

RECOMMENDED APPLICATION VOLTAGE ⁽¹⁾	VOLTAGE RATING
85°C RATING	
12	25
15	35

(1) Recommended Application Voltage for AVX TPS and Sprague 594D Tantalum Chip Capacitors Derated for 85°C

表 9-11. Sprague 594D

RECOMMENDED APPLICATION VOLTAGE ⁽¹⁾	VOLTAGE RATING
85°C RATING	
2.5	4
3.3	6.3
5	10
8	16
12	20
18	25
24	35
29	50

(1) Recommended Application Voltage for AVX TPS and Sprague 594D Tantalum Chip Capacitors Derated for 85°C

Use caution when using only ceramic capacitors for input bypassing, because it can cause severe ringing at the V_{IN} pin. The important parameters for the input capacitor are the input voltage rating and the RMS current rating. With a maximum input voltage of 28 V, an aluminum electrolytic capacitor with a voltage rating of at least 35 V ($1.25 \times V_{IN}$) is required.

The RMS current rating requirement for the input capacitor in a buck regulator is approximately $\frac{1}{2}$ the DC load current. In this example, with a 500-mA load, a capacitor with an RMS current rating of at least 250 mA is required. The curves shown in 图 9-2 can be used to select an appropriate input capacitor. From the curves, locate the 35-V line and note which capacitor values have RMS current ratings greater than 250 mA.

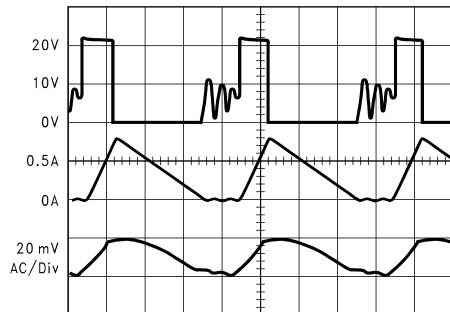
For a through-hole design, a 68- μ F, 35-V electrolytic capacitor (Panasonic HFQ series, Nichicon PL, Sanyo MV-GX series or equivalent) is adequate. Other types or other manufacturers' capacitors can be used provided the RMS ripple current ratings are adequate. Additionally, for a complete surface mount design, electrolytic capacitors such as the Sanyo CV-C or CV-BS, and the Nichicon WF or UR and the NIC Components NACZ series can be considered.

For surface mount designs, solid tantalum capacitors can be used, but caution must be exercised with regard to the capacitor surge current rating and voltage rating. In this example, checking note 1 of 表 9-5, and the Sprague 594D series datasheet, a Sprague 594D 15- μ F, 50-V capacitor is adequate.

9.2.2.2.6 Boost Capacitor (C_B)

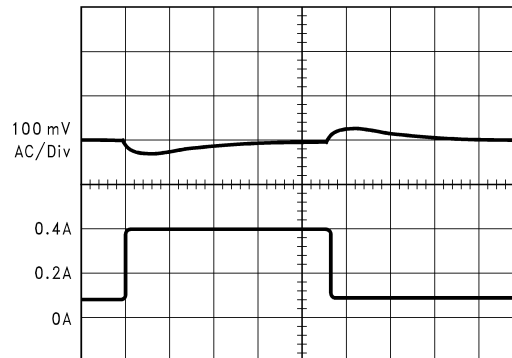
This capacitor develops the necessary voltage to turn the switch gate on fully. All applications must use a 0.01- μ F, 50-V ceramic capacitor. For this application, and all applications, use a 0.01- μ F, 50-V ceramic capacitor.

9.2.2.3 Application Curves



Discontinuous mode switching waveforms $V_{IN} = 20\text{ V}$, $V_{OUT} = 5\text{ V}$, $I_{LOAD} = 300\text{ mA}$, $L = 15\text{ }\mu\text{H}$, $C_{OUT} = 68\text{ }\mu\text{F}$ ($2\times$), $C_{OUTESR} = 25\text{ m}\Omega$
A: V_{SW} pin voltage = 10 V/div
B: Inductor current = 0.5 A/div
C: Output ripple voltage = 20 mV/div ac-coupled

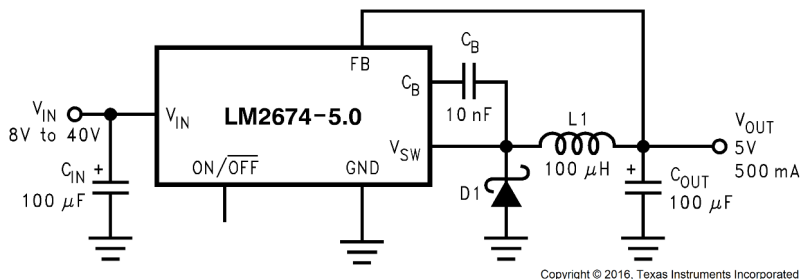
图 9-7. Horizontal Time Base: 1 $\mu\text{s}/\text{div}$



Load transient response for discontinuous mode $V_{IN} = 20\text{ V}$, $V_{OUT} = 5\text{ V}$, $L = 47\text{ }\mu\text{H}$, $C_{OUT} = 68\text{ }\mu\text{F}$, $C_{OUTESR} = 50\text{ m}\Omega$
A: Output voltage = 100 mV/div, ac-coupled
B: Load current = 100-mA to 400-mA load pulse

图 9-8. Horizontal Time Base: 200 $\mu\text{s}/\text{div}$

9.2.3 Typical Application for All Output Voltage Versions



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图 9-9. Typical Application

9.2.3.1 Application Curves

for continuous mode operation

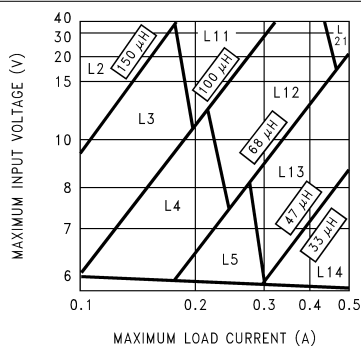


图 9-10. LM2674, 3.3-V Version

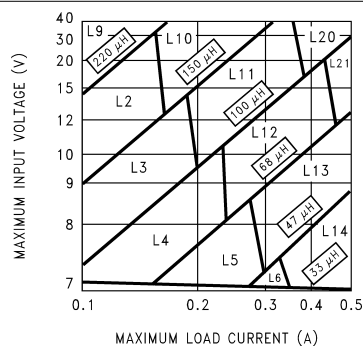


图 9-11. LM2674, 5-V Version

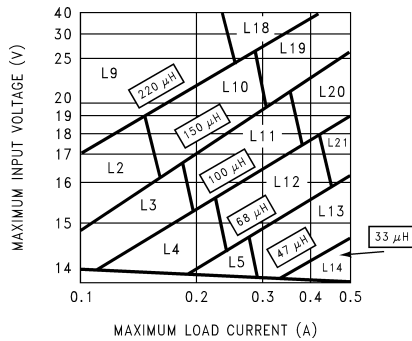


图 9-12. LM2674, 12-V Version

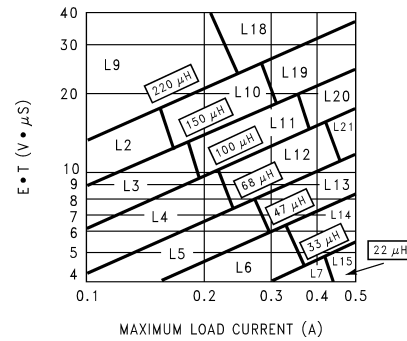


图 9-13. LM2674, Adjustable Version

9.3 Power Supply Recommendations

The LM2674 is designed to operate from an input voltage supply up to 40 V. This input supply must be well regulated and able to withstand maximum input current and maintain a stable voltage.

9.4 Layout

9.4.1 Layout Guidelines

Layout is very important in switching regulator designs. Rapidly switching currents associated with wiring inductance can generate voltage transients which can cause problems. For minimal inductance and ground loops, the wires indicated by heavy lines (in 图 9-1 and 图 9-5) must be wide printed-circuit traces and must be kept as short as possible. For best results, external components must be placed as close to the switcher IC as possible using ground plane construction or single point grounding.

If open core inductors are used, take special care as to the location and positioning of this type of inductor. Allowing the inductor flux to intersect sensitive feedback, IC ground path, and C_{OUT} wiring can cause problems.

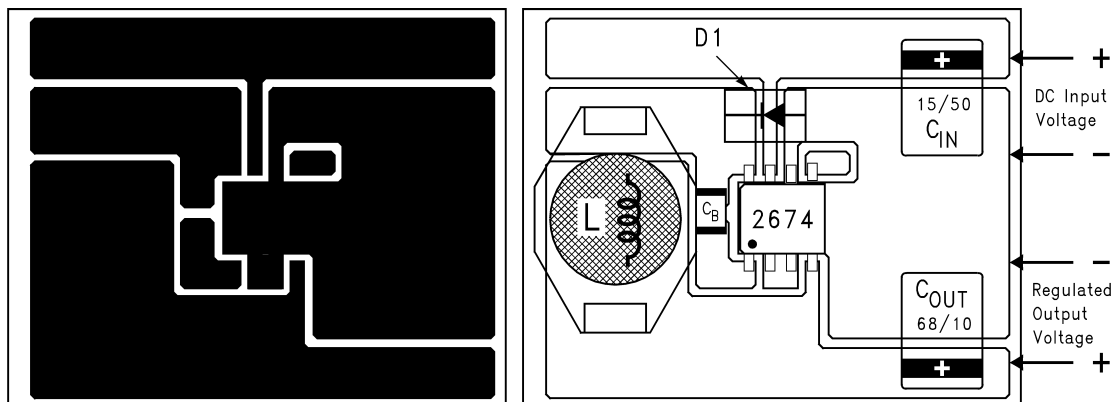
When using the adjustable version, take special care as to the location of the feedback resistors and the associated wiring. Physically place both resistors near the IC, and route the wiring away from the inductor, especially an open core type of inductor.

9.4.1.1 WSON Package Devices

The LM2674 is offered in the 16-pin WSON surface mount package to allow for increased power dissipation compared to the 8-pin SOIC and PDIP.

The die attach pad (DAP) must be connected to PCB ground plane. For CAD and assembly guidelines refer to [AN-1187 Leadless Leadframe Package \(LLP\)](#) application report.

9.4.2 Layout Examples

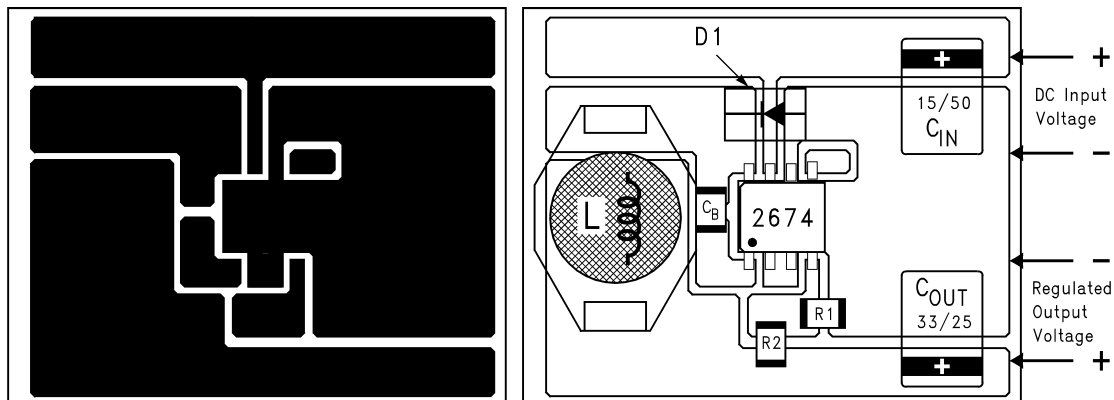


C_{IN} = 15- μ F, 25-V, Solid Tantalum Sprague 594D series

C_{OUT} = 68- μ F, 10-V, Solid Tantalum Sprague 594D series

D1 = 1-A, 40-V Schottky Rectifier, Surface Mount
L1 = 47- μ H, L13, Coilcraft DO3308
C_B = 0.01- μ F, 50-V Ceramic

图 9-14. Typical Surface-Mount PCB Layout, Fixed Output (4x Size)



C_{IN} = 15- μ F, 50-V, Solid Tantalum Sprague 594D series
C_{OUT} = 33- μ F, 25-V, Solid Tantalum Sprague 594D series
D1 = 1-A, 40-V Schottky Rectifier, Surface Mount
L1 = 100- μ H, L20, Coilcraft DO3316
C_B = 0.01- μ F, 50-V Ceramic
R1 = 1k, 1%
R2 = Use formula in [Detailed Design Procedure](#)

图 9-15. Typical Surface-Mount PCB Layout, Adjustable Output (4x Size)

10 Device and Documentation Support

10.1 Device Support

10.1.1 Development Support

For development support see the following:

- For TI's WEBENCH Design Environment, visit the [WEBENCH Design Center](#)

10.1.1.1 Custom Design with WEBENCH® Tools

[Click here](#) to create a custom design using the LM2674 devices with the WEBENCH Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

10.2 Documentation Support

10.2.1 Related Documentation

For related documentation see the following:

Texas Instruments, [AN-1187 Leadless Leadframe Package \(LLP\)](#) application report

10.3 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

10.4 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《[使用条款](#)》。

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ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

10.7 术语表

TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM2674LD-ADJ/NOPB	ACTIVE	WSON	NHN	16	1000	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 125	S000CB	Samples
LM2674LDX-5.0/NOPB	ACTIVE	WSON	NHN	16	4500	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 125	S000BB	Samples
LM2674M-12	LIFEBUY	SOIC	D	8	95	Non-RoHS & Green	Call TI	Level-1-235C-UNLIM	-40 to 125	2674 M-12	
LM2674M-12/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 M-12	Samples
LM2674M-3.3/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 M3.3	Samples
LM2674M-5.0	LIFEBUY	SOIC	D	8	95	Non-RoHS & Green	Call TI	Level-1-235C-UNLIM	-40 to 125	2674 M5.0	
LM2674M-5.0/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 M5.0	Samples
LM2674M-ADJ/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 MADJ	Samples
LM2674MX-12/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 M-12	Samples
LM2674MX-3.3/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 M3.3	Samples
LM2674MX-5.0/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 M5.0	Samples
LM2674MX-ADJ/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2674 MADJ	Samples
LM2674N-3.3/NOPB	ACTIVE	PDIP	P	8	40	RoHS & Green	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2674 N-3.3	Samples
LM2674N-5.0/NOPB	ACTIVE	PDIP	P	8	40	RoHS & Green	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2674 N-5.0	Samples
LM2674N-ADJ/NOPB	ACTIVE	PDIP	P	8	40	RoHS & Green	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2674 N-ADJ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

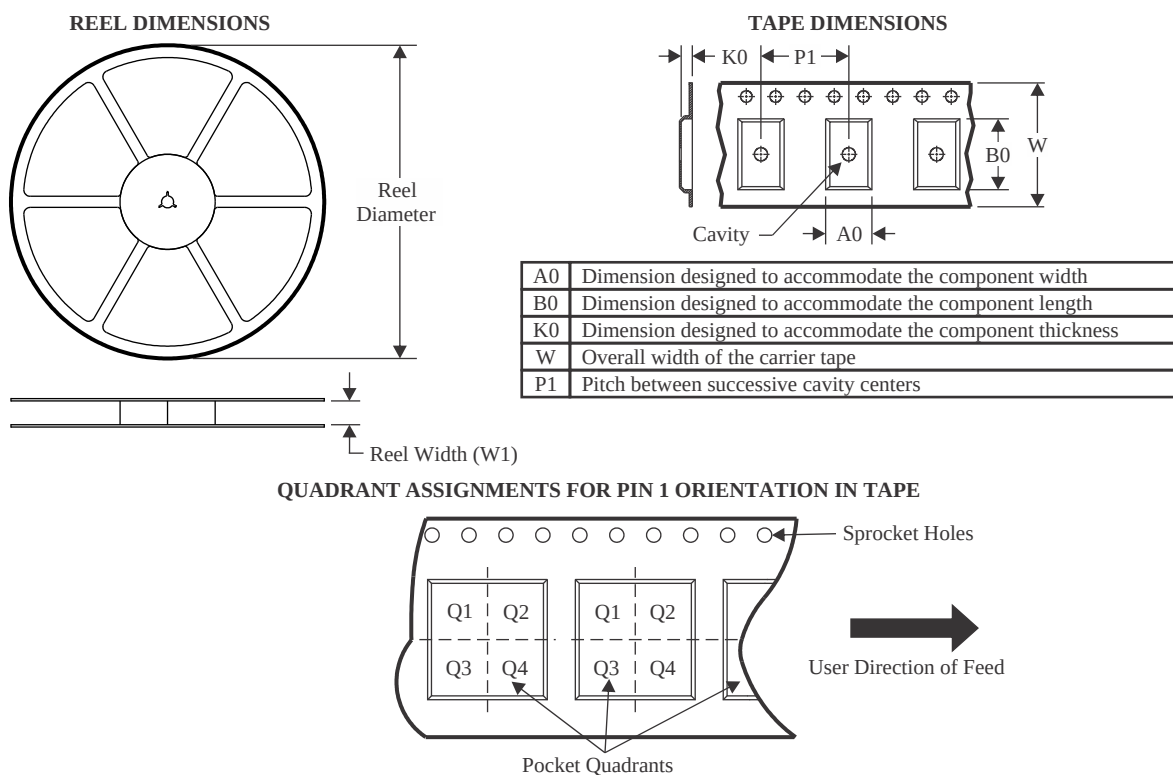
⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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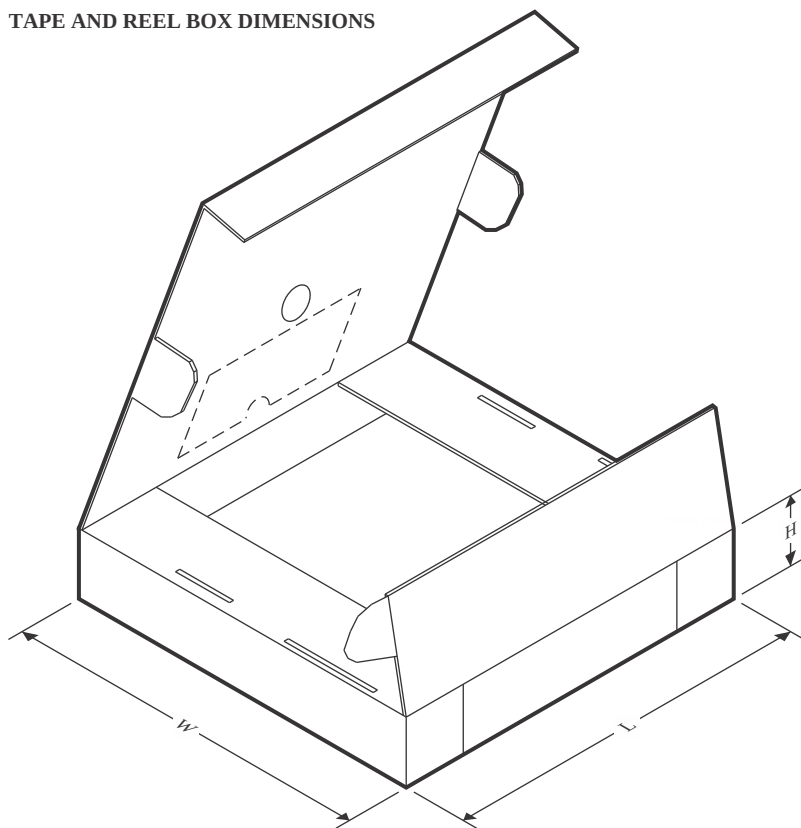
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2674LD-ADJ/NOPB	WSO	NHN	16	1000	178.0	12.4	5.3	5.3	1.3	8.0	12.0	Q1
LM2674LDX-5.0/NOPB	WSO	NHN	16	4500	330.0	12.4	5.3	5.3	1.3	8.0	12.0	Q1
LM2674MX-12/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2674MX-3.3/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2674MX-5.0/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2674MX-ADJ/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

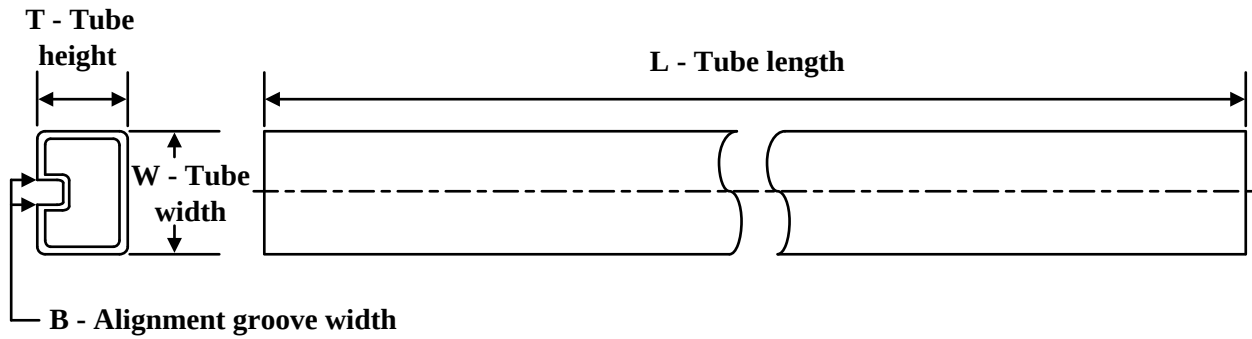
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2674LD-ADJ/NOPB	WSO	NHN	16	1000	208.0	191.0	35.0
LM2674LDX-5.0/NOPB	WSO	NHN	16	4500	356.0	356.0	36.0
LM2674MX-12/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2674MX-3.3/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2674MX-5.0/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2674MX-ADJ/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

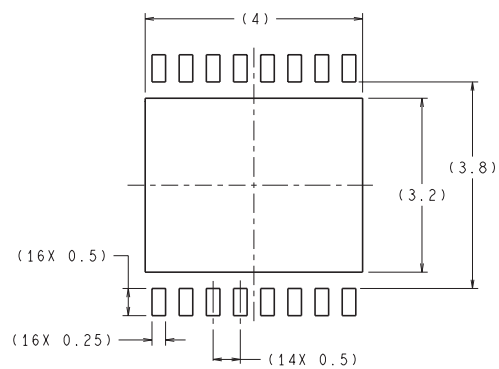
TUBE



*All dimensions are nominal

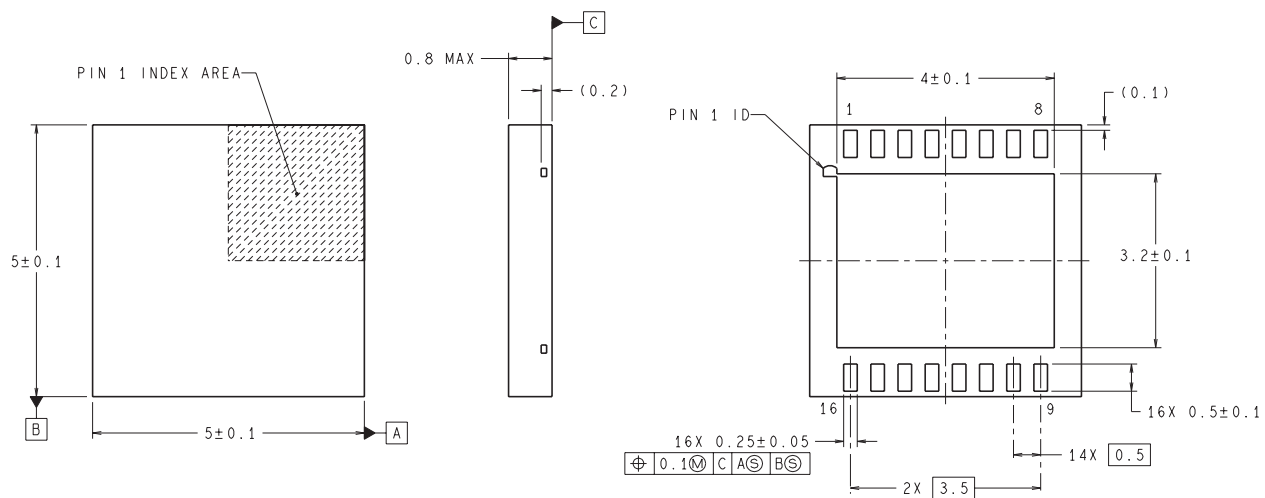
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LM2674M-12	D	SOIC	8	95	495	8	4064	3.05
LM2674M-12	D	SOIC	8	95	495	8	4064	3.05
LM2674M-12/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2674M-3.3/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2674M-5.0	D	SOIC	8	95	495	8	4064	3.05
LM2674M-5.0	D	SOIC	8	95	495	8	4064	3.05
LM2674M-5.0/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2674M-ADJ/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2674N-3.3/NOPB	P	PDIP	8	40	502	14	11938	4.32
LM2674N-5.0/NOPB	P	PDIP	8	40	502	14	11938	4.32
LM2674N-ADJ/NOPB	P	PDIP	8	40	502	14	11938	4.32

NHN0016A

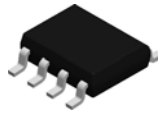


RECOMMENDED LAND PATTERN
1:1 RATIO WITH PKG SOLDER PADS

DIMENSIONS ARE IN MILLIMETERS



LDA16A (REV A)

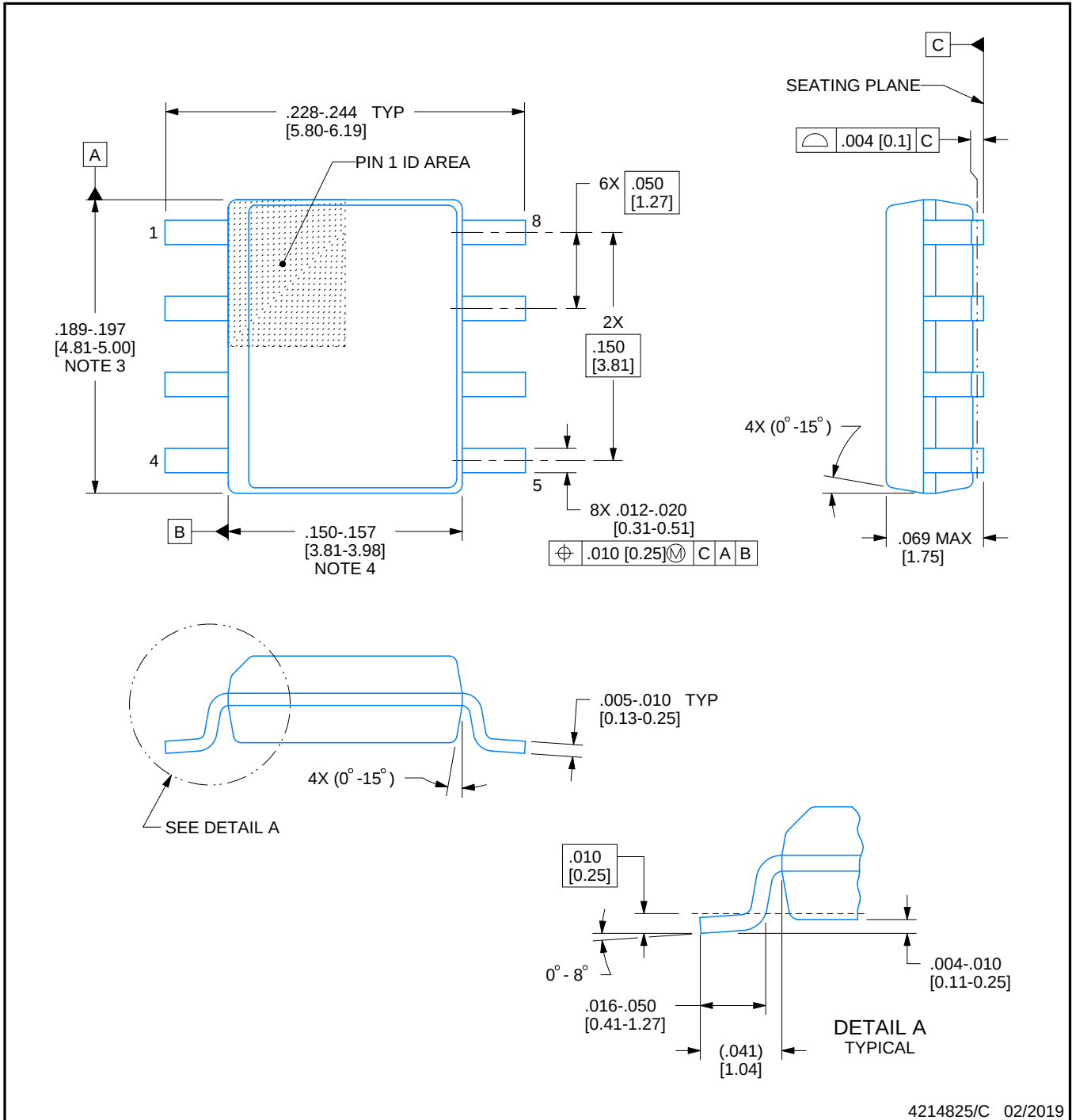


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

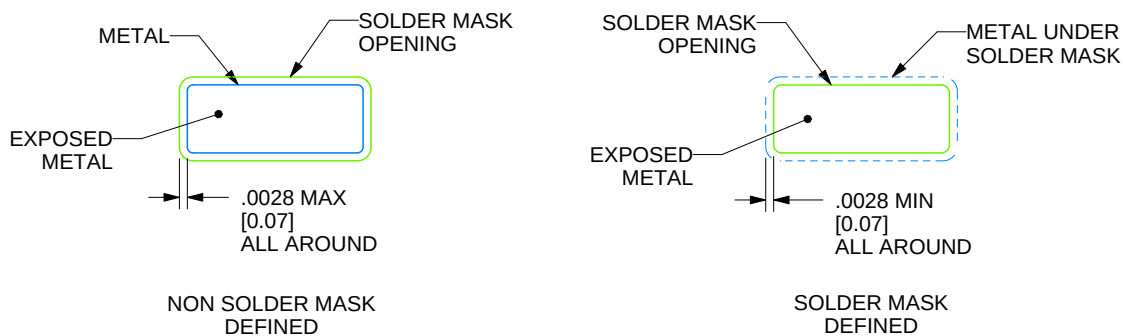
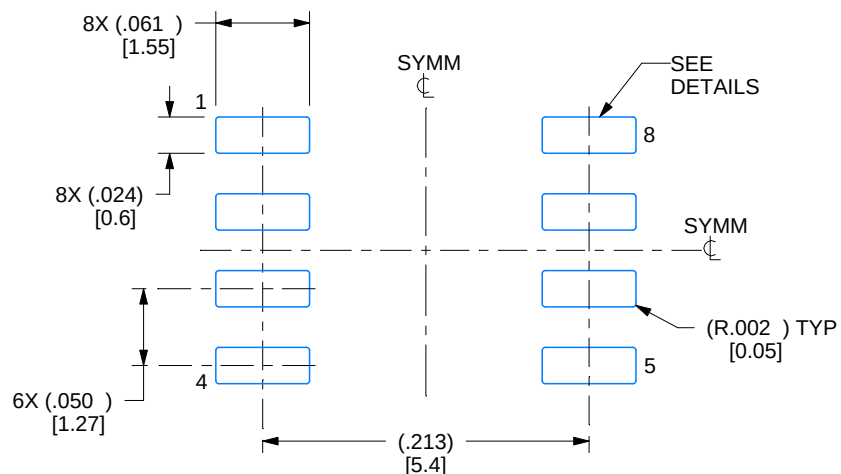
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

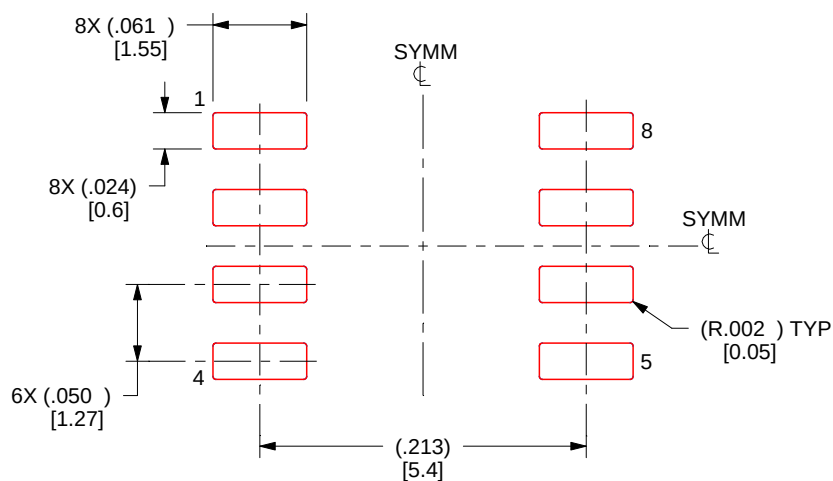
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

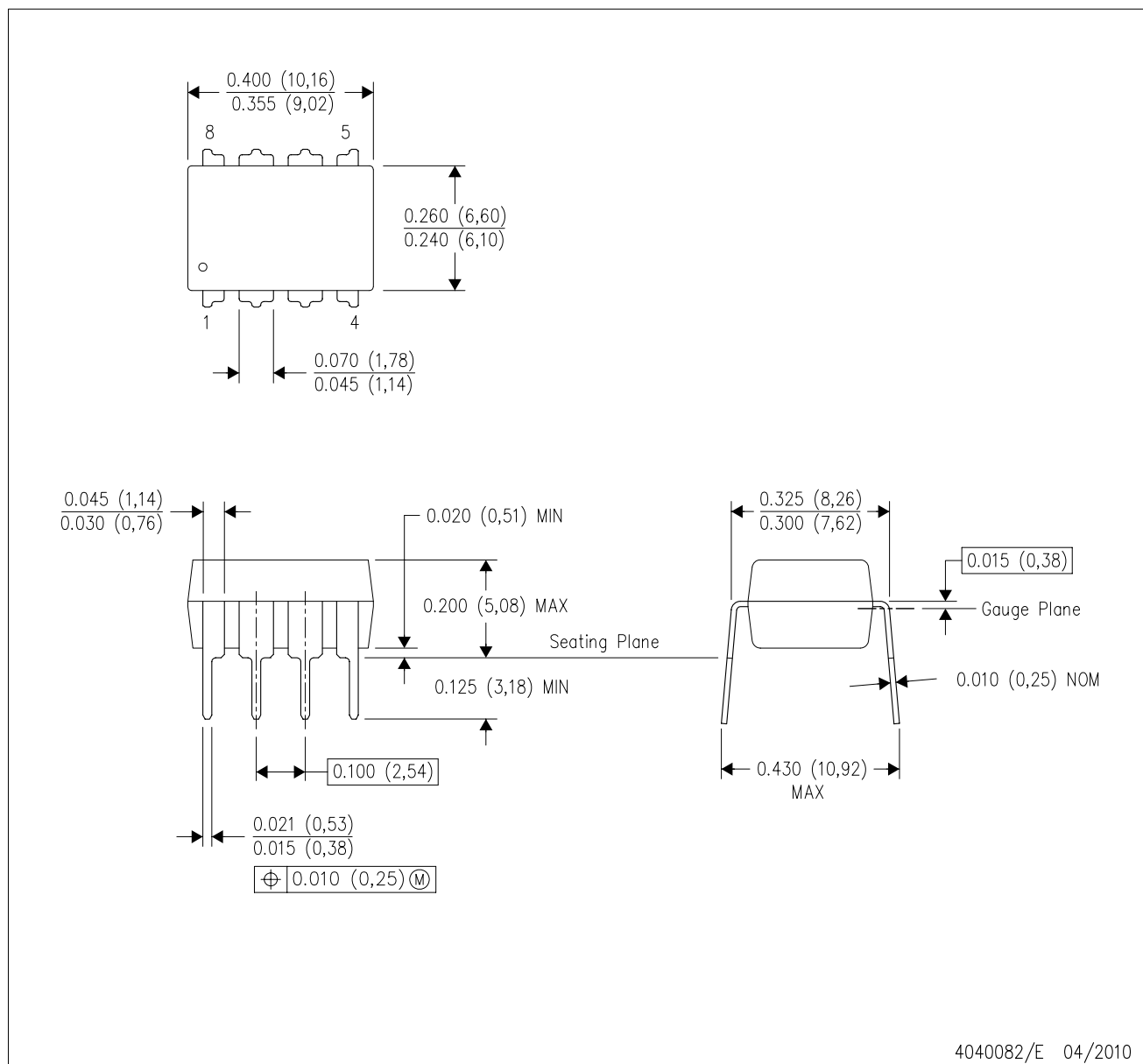
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

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